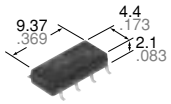
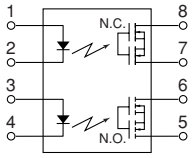
NAiS

Super miniature design, SOP (1Form A/1Form B) 8-pin type. Controls load voltage 350V.

GU PhotoMOS (AQW610S)



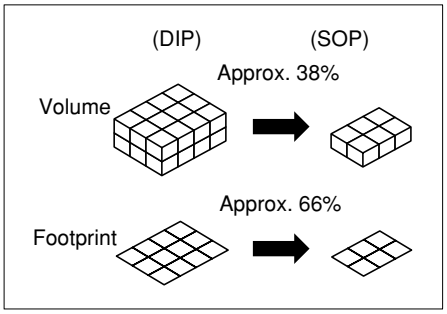
mm inch



FEATURES

1. 2 channels in super miniature design

The device comes in a super-miniature SO package measuring (W) 4.4 × (L) 9.37 × (H) 2.1 mm (W) .173× (L) .369× (H) .083 inch —approx. 38% of the volume and 66% of the footprint size of DIP type PhotoMOS Relays.



2. Tape and reel

The device comes standard in a tape and reel (1,000 pcs./reel) to facilitate automatic insertion machines.

Applicable for 1 Form A 1 Form B use as well as two independent 1 Form A and 1 Form B use

Controls low-level analog signals

PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion

5. Low-level off state leakage current

TYPICAL APPLICATIONS

- Telephones
- Measuring instruments
- Computer
- Industrial robots
- High-speed inspection machines.

TYPES

1. AC/DC type

Output rating*		Part No.		Packing quantity in tape and reel
Load voltage	Load current	Picked from the 1/2/3/4-pin side	Picked from the 5/6/7/8-pin side	
350 V	100 mA	AQW610SX	AQW610SZ	1,000 pcs.

*Indicate the peak AC and DC values.

Notes: (1) Tape package is the standard packing style. Also available in tube. (Part No. suffix "X" or "Z" is not needed when ordering; Tube: 50 pcs.; Case: 1,000 pcs.)

(2) For space reasons, the package type indicator "X" and "Z" are omitted from the seal.

RATING

1. AC/DC type

1. Absolute maximum ratings (Ambient temperature : 25°C 77°F)

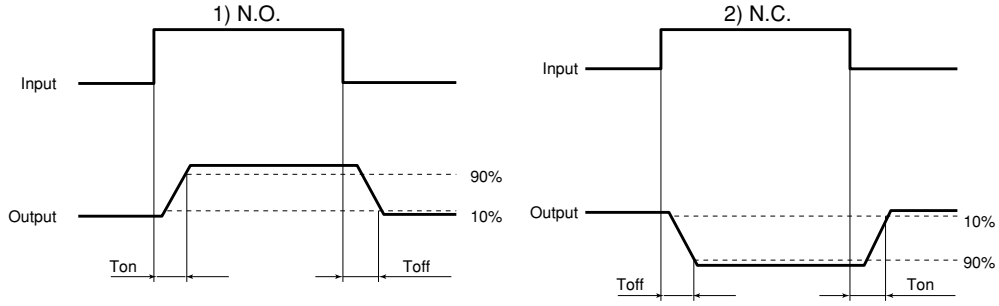
Item		Symbol	AQW610S	Remarks
Input	LED forward current	I_F	50 mA	
	LED reverse voltage	V_R	5 V	
	Peak forward current	I_{FP}	1 A	f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P_{in}	75 mW	
Output	Load voltage (peak AC)	V_L	350 V	
	Continuous load current	I_L	0.1 A (0.13 A)	Peak AC, DC ( ): in case of using only 1a or 1b, 1 channel
	Peak load current	I_{peak}	0.3 A	100 ms (1 shot), V_L = DC
	Power dissipation	P_{out}	600 mW	
Total power dissipation		P_T	650 mW	
I/O isolation voltage		V_{iso}	1,500 V AC	
Temperature limits	Operating	T_{opr}	–40°C to +85°C –40°F to +185°F	Non-condensing at low temperatures
	Storage	T_{stg}	–40°C to +100°C –40°F to +212°F	

2. Electrical characteristics (Ambient temperature : 25°C 77°F)

Item			Symbol	AQW610S	Condition
Input	LED operate current	Typical	I_{Fon}	0.9 mA	I_L = Max.
		Maximum		3 mA	
	LED reverse current	Minimum	I_{Foff}	0.4 mA	I_L = Max.
		Typical		0.8 mA	
	LED dropout voltage	Typical	V_F	1.25 V (1.14 V at I_F = 5 mA)	I_F = 50 mA
		Maximum		1.5 V	
Output	On resistance	Typical	R_{on}	18 Ω	I_F = 5 mA (N.O.) I_F= 0 mA (N.C.) I_L = Max. Within 1 s on time
		Maximum		25 Ω	
	Off state leakage current	Maximum	I_{leak}	1 μA	I_F = 0 mA (N.O.) I_F= 5 mA (N.C.) V_L = Max.
Transfer characteristics	Operate time*	Typical	T_{on}	0.28 ms (N.O.), 0.52 ms (N.C.)	I_F = 0 mA → 5 mA I_L = Max.
		Maximum		1.0 ms	
	Reverse time*	Typical	T_{off}	0.04 ms (N.O.), 0.23 ms (N.C.)	I_F = 5 mA → 0 mA I_L = Max.
		Maximum		1.0 ms	
	I/O capacitance	Typical	C_{iso}	0.8 pF	f = 1 MHz V_B = 0 V
		Maximum		1.5 pF	
	Initial I/O isolation resistance	Minimum	R_{iso}	1,000 MΩ	500 V DC

Note: Recommendable LED forward current I_F = 5 mA. For type of connection

*Operate/Reverse time

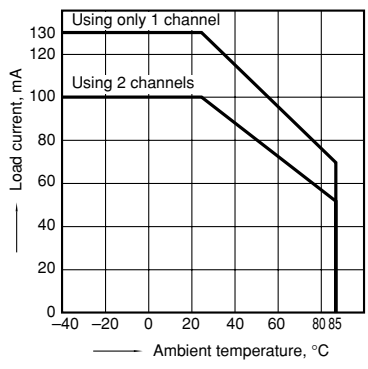


■ For Dimensions
■ For Schematic and Wiring Diagrams
■ For Cautions for Use

REFERENCE DATA

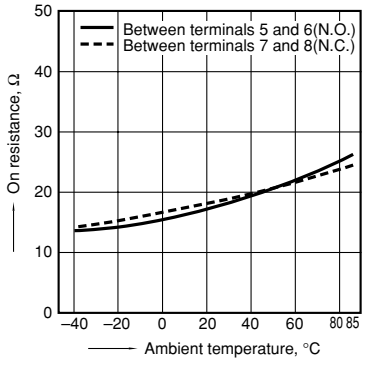
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: –40°C to +85°C
–40°F to +185°F



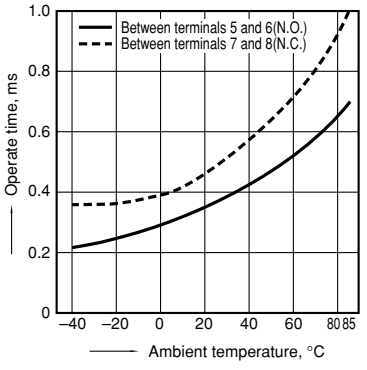
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8; LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



3. Operate time vs. ambient temperature characteristics

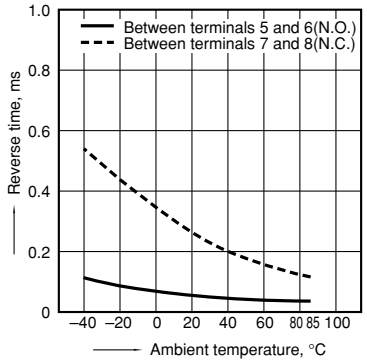
LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



GU PhotoMOS (AQW610S)

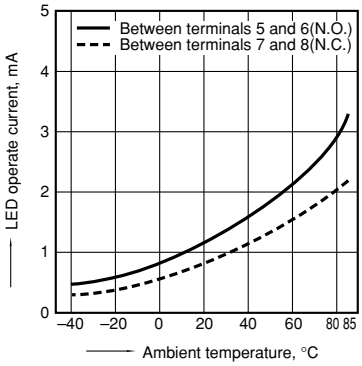
4. Reverse time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



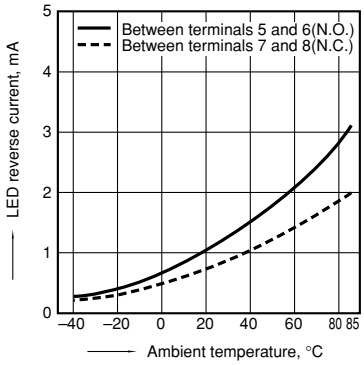
5. LED operate current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



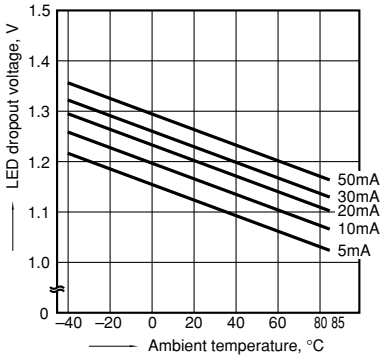
6. LED reverse current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



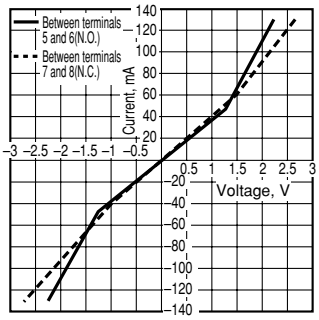
7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



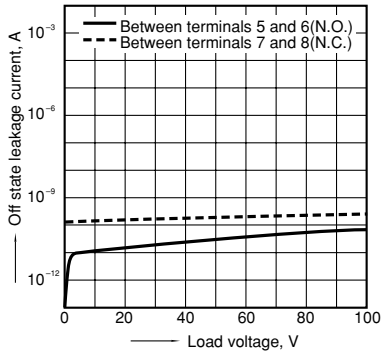
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8;
Ambient temperature: 25°C 77°F



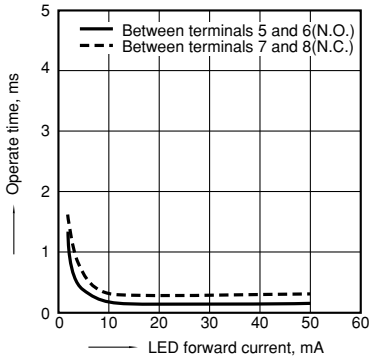
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Ambient temperature: 25°C 77°F



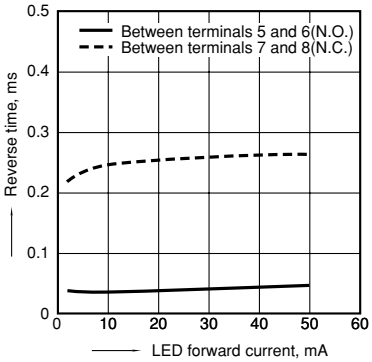
10. Operate time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F



11. Reverse time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Frequency: 1 MHz;
Ambient temperature: 25°C 77°F